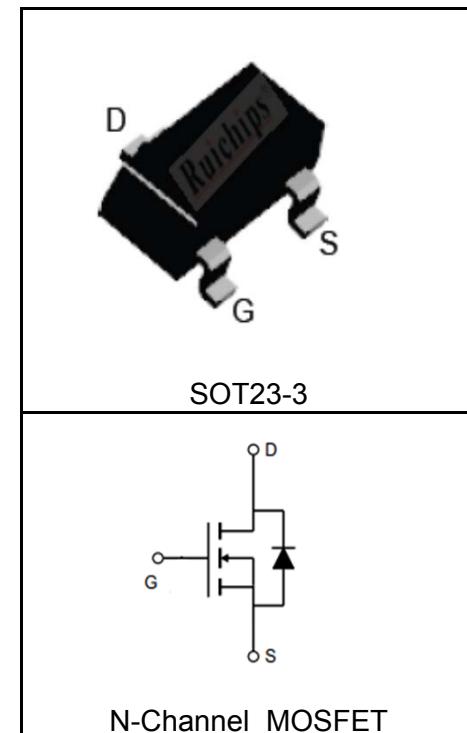


### Features

- 20V/6A,
- $R_{DS\ (ON)} = 10\text{m}\Omega$ (Typ.)@ $V_{GS}=4.5\text{V}$
- $R_{DS\ (ON)} = 15\text{m}\Omega$ (Typ.)@ $V_{GS}=2.5\text{V}$
- Low  $R_{DS\ (ON)}$
- Super High Dense Cell Design
- Reliable and Rugged
- Lead Free and Green Devices Available (RoHS Compliant)

### Pin Description



### Applications

- Power Management

### Absolute Maximum Ratings

Symbol	Parameter	Rating	Unit	
<b>Common Ratings</b> ( $T_A=25^\circ\text{C}$ Unless Otherwise Noted)				
$V_{DSS}$	Drain-Source Voltage	20	V	
$V_{GSS}$	Gate-Source Voltage	$\pm 12$		
$T_J$	Maximum Junction Temperature	150	°C	
$T_{STG}$	Storage Temperature Range	-55 to 150	°C	
$I_S$	Diode Continuous Forward Current	$T_A=25^\circ\text{C}$	A	
<b>Mounted on Large Heat Sink</b>				
$I_{DP}^{(1)}$	300μs Pulse Drain Current Tested	$T_A=25^\circ\text{C}$	24	A
$I_D^{(2)}$	Continuous Drain Current( $V_{GS}=4.5\text{V}$ )	$T_A=25^\circ\text{C}$	6	A
		$T_A=70^\circ\text{C}$	4.5	
$P_D$	Maximum Power Dissipation	$T_A=25^\circ\text{C}$	1.25	W
		$T_A=70^\circ\text{C}$	0.75	
$R_{\theta JC}$	Thermal Resistance-Junction to Case	-	°C/W	
$R_{\theta JA}^{(3)}$	Thermal Resistance-Junction to Ambient	100	°C/W	
<b>Drain-Source Avalanche Ratings</b>				
$E_{AS}^{(4)}$	Avalanche Energy, Single Pulsed	TBD	mJ	

## Electrical Characteristics ( $T_A=25^\circ\text{C}$ Unless Otherwise Noted)

Symbol	Parameter	Test Condition	RU207C			Unit
			Min.	Typ.	Max.	
<b>Static Characteristics</b>						
$\text{BV}_{\text{DSS}}$	Drain-Source Breakdown Voltage	$\text{V}_{\text{GS}}=0\text{V}, \text{I}_{\text{DS}}=250\mu\text{A}$	20			V
$\text{I}_{\text{DSS}}$	Zero Gate Voltage Drain Current	$\text{V}_{\text{DS}}=20\text{V}, \text{V}_{\text{GS}}=0\text{V}$			1	$\mu\text{A}$
		$\text{T}_J=125^\circ\text{C}$			30	
$\text{V}_{\text{GS(th)}}$	Gate Threshold Voltage	$\text{V}_{\text{DS}}=\text{V}_{\text{GS}}, \text{I}_{\text{DS}}=250\mu\text{A}$	0.5	0.7	1.5	V
$\text{I}_{\text{GSS}}$	Gate Leakage Current	$\text{V}_{\text{GS}}=\pm 10\text{V}, \text{V}_{\text{DS}}=0\text{V}$			$\pm 100$	nA
$\text{R}_{\text{DS(ON)}}^{(5)}$	Drain-Source On-state Resistance	$\text{V}_{\text{GS}}=4.5\text{V}, \text{I}_{\text{DS}}=6\text{A}$		10	13	m $\Omega$
		$\text{V}_{\text{GS}}=2.5\text{V}, \text{I}_{\text{DS}}=5\text{A}$		15	18	m $\Omega$
<b>Diode Characteristics</b>						
$\text{V}_{\text{SD}}^{(5)}$	Diode Forward Voltage	$\text{I}_{\text{SD}}=1\text{A}, \text{V}_{\text{GS}}=0\text{V}$			1	V
$\text{t}_{\text{rr}}$	Reverse Recovery Time	$\text{I}_{\text{SD}}=1\text{A}, \frac{d\text{I}_{\text{SD}}}{dt}=100\text{A}/\mu\text{s}$		15		ns
$\text{Q}_{\text{rr}}$	Reverse Recovery Charge			8		nC
<b>Dynamic Characteristics<sup>(6)</sup></b>						
$\text{R}_G$	Gate Resistance	$\text{V}_{\text{GS}}=0\text{V}, \text{V}_{\text{DS}}=0\text{V}, \text{F}=1\text{MHz}$		1.5		$\Omega$
$\text{C}_{\text{iss}}$	Input Capacitance	$\text{V}_{\text{GS}}=0\text{V}, \text{V}_{\text{DS}}=10\text{V}, \text{Frequency}=1.0\text{MHz}$		590		pF
$\text{C}_{\text{oss}}$	Output Capacitance			125		
$\text{C}_{\text{rss}}$	Reverse Transfer Capacitance			90		
$\text{t}_{\text{d(ON)}}$	Turn-on Delay Time	$\text{V}_{\text{DD}}=10\text{V}, \text{I}_{\text{DS}}=6\text{A}, \text{V}_{\text{GEN}}=4.5\text{V}, \text{R}_G=6\Omega$		8		ns
$\text{t}_{\text{r}}$	Turn-on Rise Time			15		
$\text{t}_{\text{d(OFF)}}$	Turn-off Delay Time			33		
$\text{t}_{\text{f}}$	Turn-off Fall Time			13		
<b>Gate Charge Characteristics<sup>(6)</sup></b>						
$\text{Q}_g$	Total Gate Charge	$\text{V}_{\text{DS}}=16\text{V}, \text{V}_{\text{GS}}=4.5\text{V}, \text{I}_{\text{DS}}=6\text{A}$		10		nC
$\text{Q}_{\text{gs}}$	Gate-Source Charge			1.6		
$\text{Q}_{\text{gd}}$	Gate-Drain Charge			3.4		

Notes: (1)Pulse width limited by safe operating area.

(2)Calculated continuous current based on maximum allowable junction temperature.

(3)When mounted on 1 inch square copper board,  $t \leq 10\text{sec}$ . The value in any given application depends on the user's specific board design.

(4)Limited by  $T_{J\text{max}}$ . Starting  $T_J = 25^\circ\text{C}$ .

(5)Pulse test; Pulse width  $\leq 300\mu\text{s}$ , duty cycle  $\leq 2\%$ .

(6)Guaranteed by design, not subject to production testing.

## Ordering and Marking Information

Device	Marking <sup>①</sup>	Package	Packaging	Quantity	Reel Size	Tape width
RU207C	4XYWW	SOT23-3	Tape&Reel	3000	7"	8mm

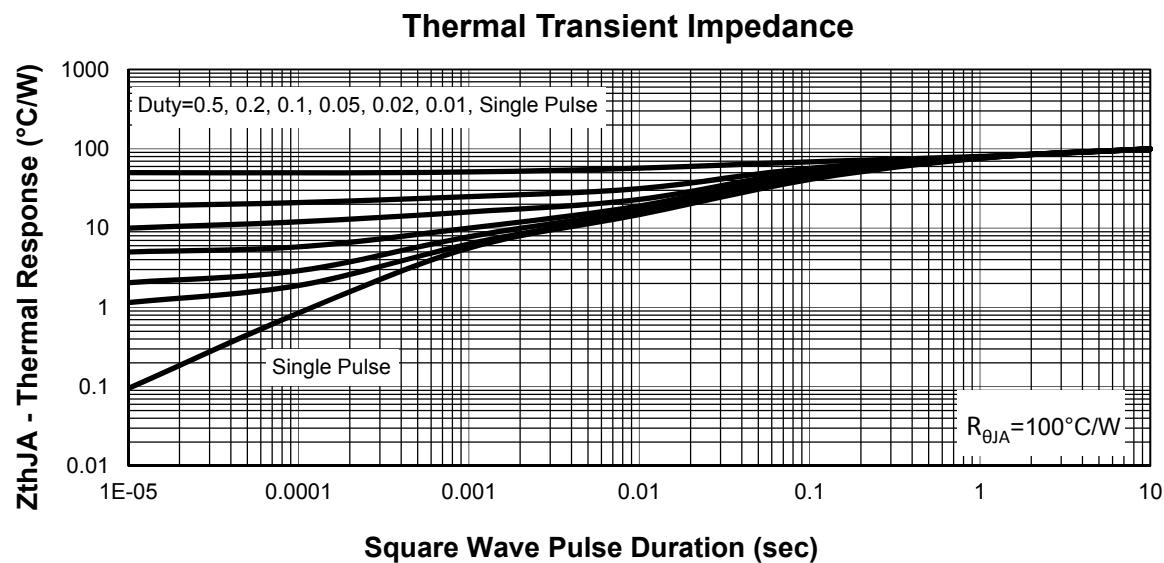
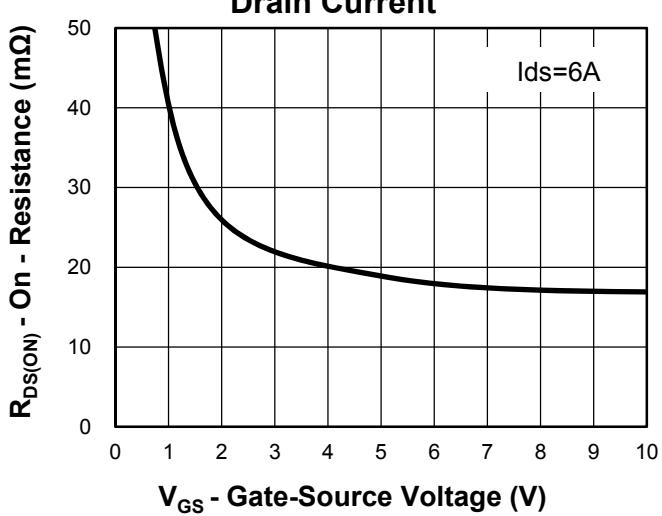
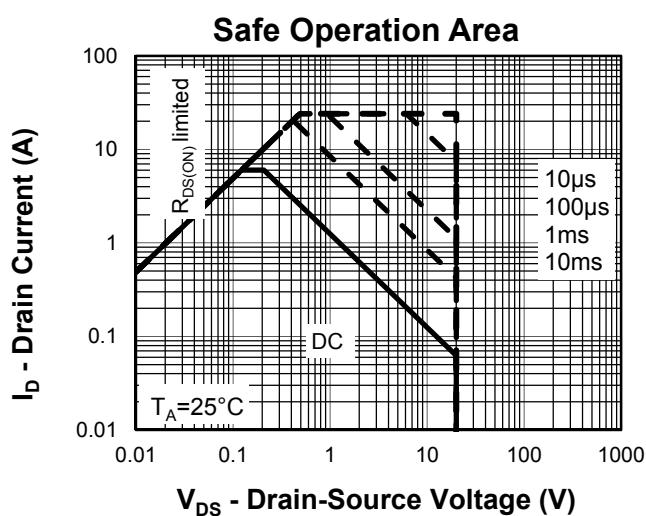
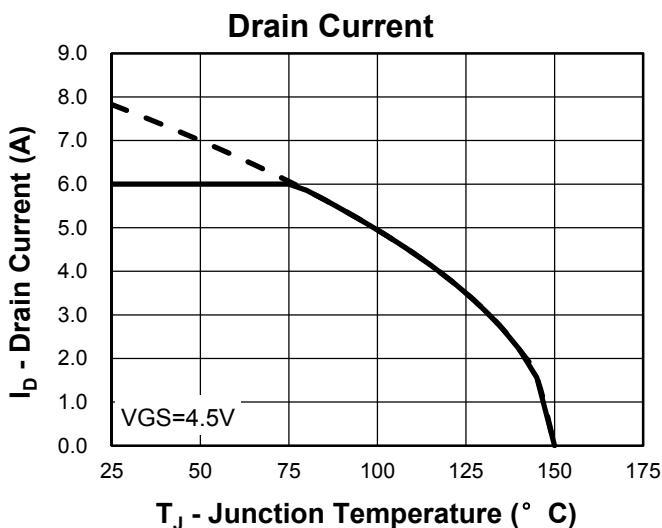
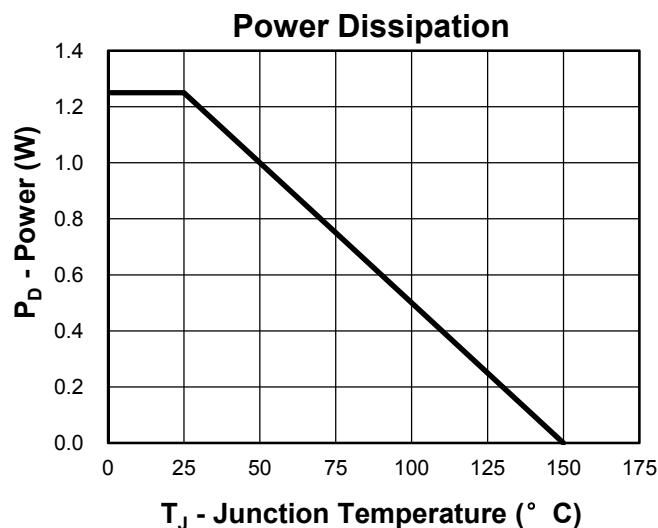
① The following characters could be different and means:

X =Assembly site code

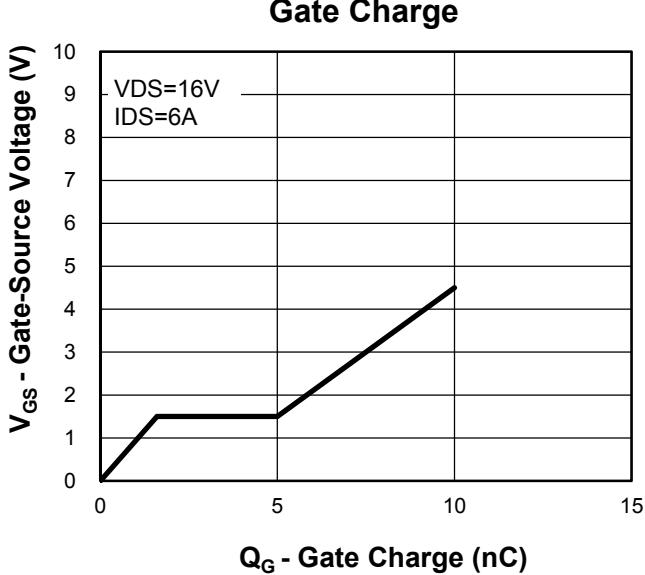
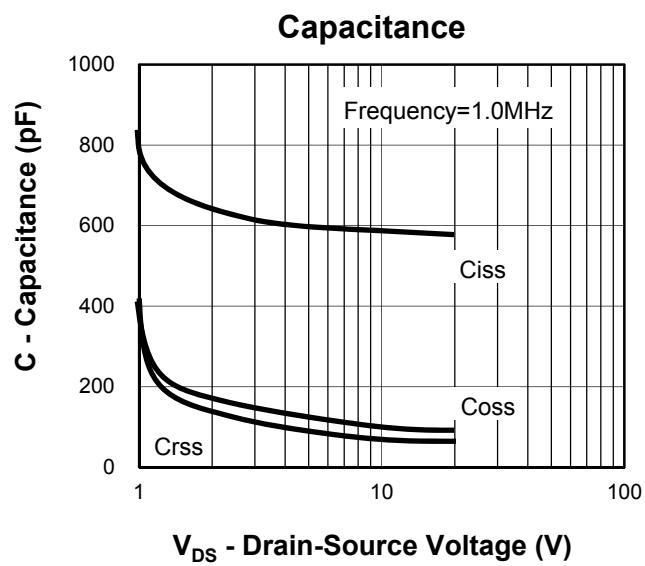
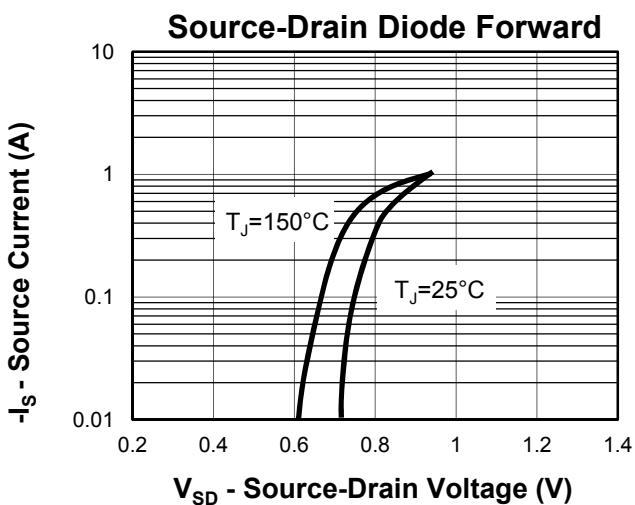
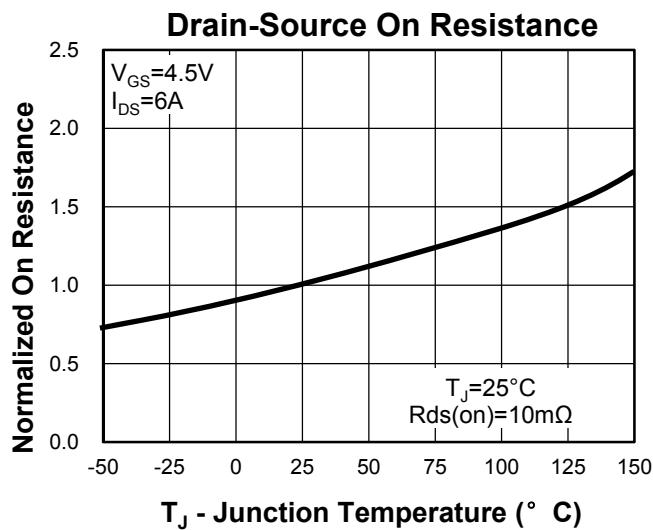
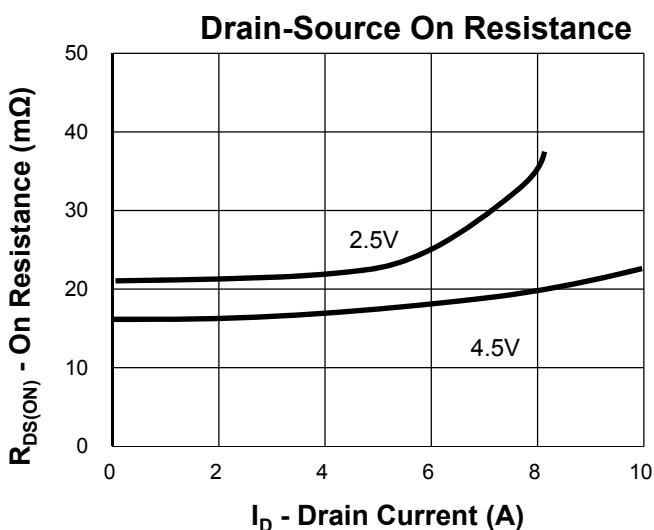
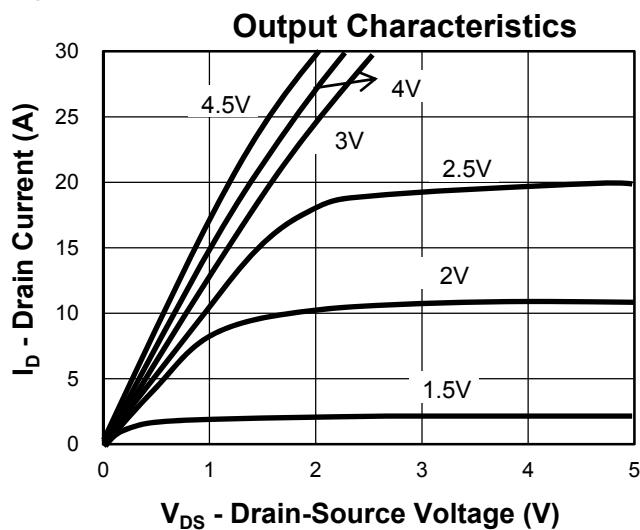
Y =Year

WW =Work Week

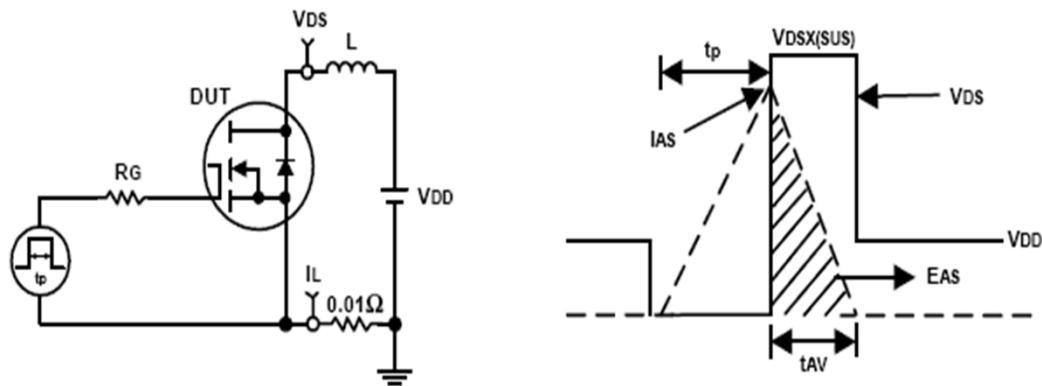
### Typical Characteristics



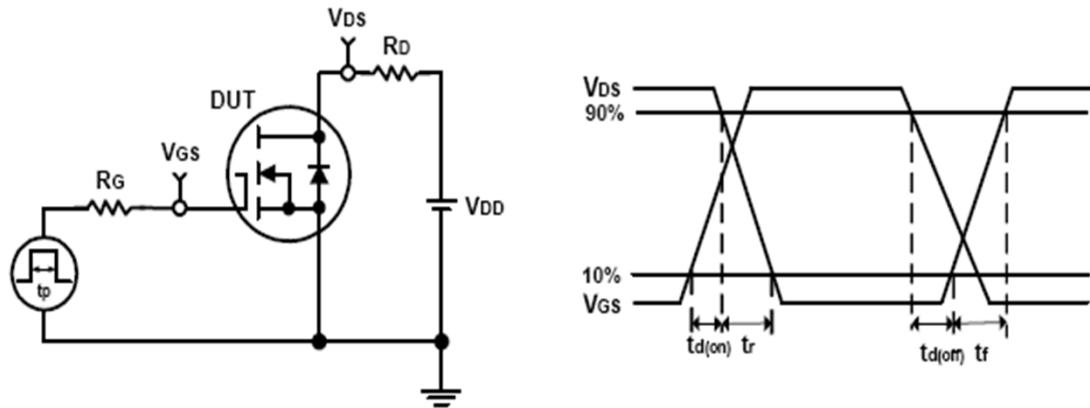
### Typical Characteristics



### Avalanche Test Circuit and Waveforms

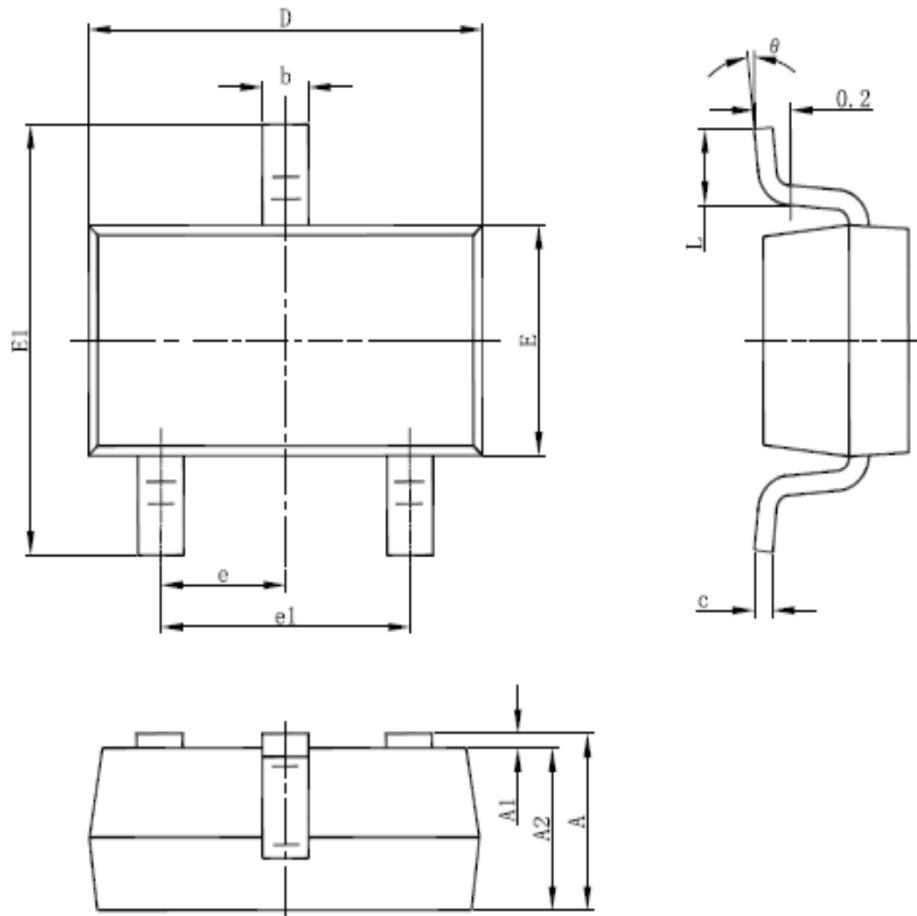


### Switching Time Test Circuit and Waveforms



## Package Information

SOT23-3



SYMBOL	MM			INCH		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.950	1.150	1.450	0.037	0.045	0.057
A1	0.000	*	0.150	0.000	*	0.006
A2	0.900	1.100	1.300	0.035	0.043	0.051
b	0.300	0.400	0.500	0.012	0.016	0.020
c	0.080	0.150	0.200	0.003	0.006	0.008
D	2.800	2.925	3.050	0.110	0.115	0.120
E	1.500	1.600	1.750	0.059	0.063	0.069
E1	2.650	2.800	3.000	0.104	0.110	0.118
e	0.950 BSC			0.037 BSC		
e1	1.800	1.900	2.000	0.071	0.075	0.079
L	0.300	0.450	0.600	0.012	0.018	0.024
θ	0°	4°	8°	0°	4°	8°

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